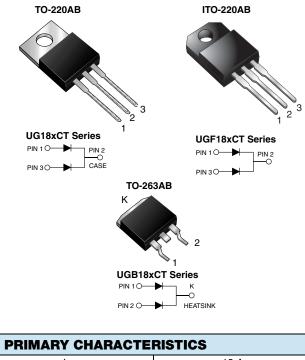
### UG18xCT, UGF18xCT, UGB18xCT

Vishay General Semiconductor

RoHS

COMPLIANT

### **Dual Common Cathode Ultrafast Plastic Rectifier**



FRIMANT ONANAOTENISTIOS					
I <sub>F(AV)</sub>	18 A				
V <sub>RRM</sub>	50 V to 200 V				
I <sub>FSM</sub>	175 A				
t <sub>rr</sub>	20 ns 0.95 V				
V <sub>F</sub> at I <sub>F</sub>					
T <sub>J</sub> max.	150 °C				
Package	TO-220AB, ITO-220AB, TO-263AB				
Diode variations	Common cathode				

#### **FEATURES**

- Power pack
- · Glass passivated chip junction
- Ultrafast recovery time
- · Low switching losses, high efficiency
- Low forward voltage drop
- · High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 275 °C max., 10 s per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 gualified
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

#### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, DC/DC converters, and other power switching application.

#### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> ( $T_c = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	SYMBOL	UG18ACT	UG18BCT	UG18CCT	UG18DCT	UNIT	
Max. repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	150	200	V	
Max. RMS voltage	V <sub>RMS</sub>	35	70	105	140	V	
Max. DC blocking voltage	V <sub>DC</sub>	50	100	150	200	V	
Max. average forward rectified current at $T_C$ = 105 °C	I <sub>F(AV)</sub>		А				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	175				А	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 65 to + 150 °C					
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V <sub>AC</sub>	1500				V	



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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_c = 25 \text{ °C}$ unless otherwise noted)								
PARAMETER	TEST CONDIT	TIONS	SYMBOL	DL UG18ACT UG18BCT UG18CCT UG18D			UG18DCT	UNIT
Max. instantaneous forward voltage per diode <sup>(1)</sup>	9.0 A		V <sub>F</sub>	1.1				
	20 A	$T_J = 100 \ ^\circ C$		1.2				
	5.0 A							
Max. DC reverse current at		T <sub>A</sub> = 25 °C	I <sub>R</sub>	10				μA
rated DC blocking voltage per diode		T <sub>A</sub> = 100 °C		300				
Max. reverse recovery time per diode	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A},$	5 A, I <sub>R</sub> = 1.0 A, I <sub>rr</sub> = 0.25 A t <sub>rr</sub>		20				ns
Max. reverse recovery time per diode	$I_{\rm F} = 9.0 \text{ A}, V_{\rm R} = 30 \text{ V},$	T <sub>J</sub> = 25 °C		30				
	dl/dt = 50 A/µs, I <sub>rr</sub> = 10 % I <sub>RM</sub>	T <sub>J</sub> = 100 °C	t <sub>rr</sub>		5	60		ns
Max. stored charge per diode	$I_{\rm F} = 9.0  \text{A},  V_{\rm R} = 30  \text{V},$	T <sub>J</sub> = 25 °C		20				
	dl/dt = 50 A/µs, I <sub>rr</sub> = 10 % I <sub>RM</sub>	T <sub>J</sub> = 100 °C	T <sub>J</sub> = 100 °C		45			nC
Typical junction capacitance per diode	at 4.0 V, 1 MHz		CJ	30				pF

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<b>THERMAL CHARACTERISTICS</b> ( $T_c = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER SYMBOL UG18 UGF18 UGB18 UN							
Typical thermal resistance from junction to case per diode	R <sub>0JC</sub>	4.0	6.0	4.0	°C/W		

ORDERING INFORMATION (EXAMPLE)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	UG18DCT-E3/45	1.85	45	50/tube	Tube			
ITO-220AB	UGF18DCT-E3/45	2.00	45	50/tube	Tube			
TO-263AB	UGB18DCT-E3/45	1.35	45	50/tube	Tube			
TO-263AB	UGB18DCT-E3/81	1.35	81	800/reel	Tape and reel			
TO-220AB	UG18DCTHE3/45 (1)	1.85	45	50/tube	Tube			
ITO-220AB	UGF18DCTHE3/45 <sup>(1)</sup>	2.00	45	50/tube	Tube			
TO-263AB	UGB18DCTHE3/45 <sup>(1)</sup>	1.35	45	50/tube	Tube			
TO-263AB	UGB18DCTHE3/81 <sup>(1)</sup>	1.35	81	800/reel	Tape and reel			

Note

(1) AEC-Q101 qualified



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#### **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)

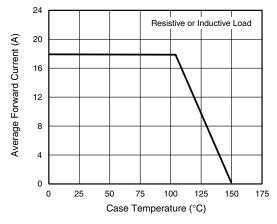


Fig. 1 - Forward Current Derating Curve

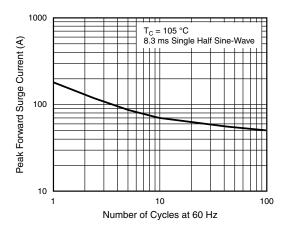


Fig. 2 - Max. Non-Repetitive Peak Forward Surge Current Per Diode

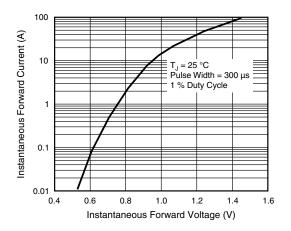


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

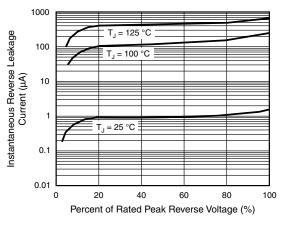


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

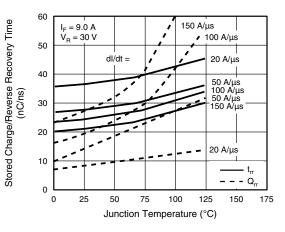


Fig. 5 - Reverse Switching Characteristics Per Diode

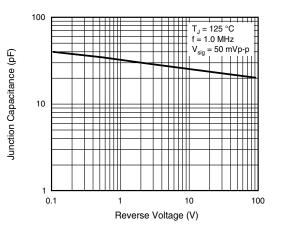


Fig. 6 - Typical Junction Capacitance Per Diode

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3

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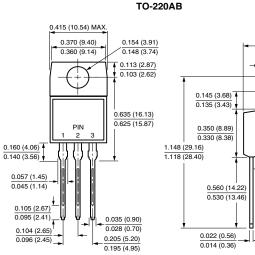


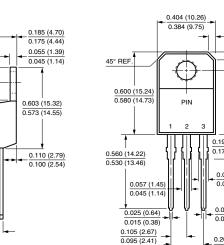
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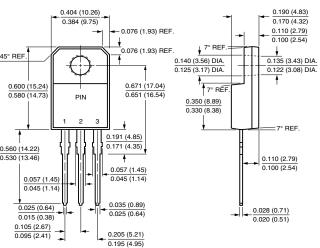
ITO-220AB

#### Vishay General Semiconductor

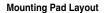
#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

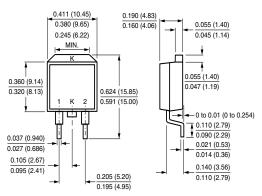






**TO-263AB** 





0.42 (10.66) MIN 0.33 (8.38) MIN 0.670 (17.02) 0.591 (15.00) 0.15 (3.81) MIN 0.08 (2.032) MIN. 0.105 (2.67) 0.095 (2.41)



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